





60V PNP MEDIUM POWER TRANSISTOR IN SOT223

Features

- BV_{CEO} > -60V
- I_C = -5A High Continuous Collector Current
- I_{CM} = -15A Peak Pulse Current
- Low Saturation Voltage V_{CE(sat)} < -140mV @ -1A
- $R_{CE(sat)} = 55m\Omega$ for a Low Equivalent On-Resistance
- h_{FE} Specified up to -10A for a High Gain Hold-Up
- Complementary NPN Type: FZT851
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- PPAP Capable (Note 4)

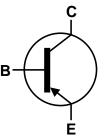
Mechanical Data

- Case: SOT223
- Case Material: Molded Plastic. "Green" Molding Compound;
 UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.112 grams (Approximate)

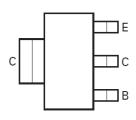








Device Symbol



Top View Pin-Out

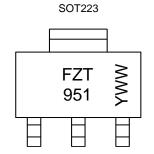
Ordering Information (Notes 4 & 5)

Product	Compliance	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
FZT951TA	AEC-Q101	FZT951	7	12	1,000
FZT951TC	AEC-Q101	FZT951	13	12	4,000
FZT951QTA	Automotive	FZT951	7	12	1,000
FZT951QTC	Automotive	FZT951	13	12	4,000

Notes: 1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.

- 2. See http://www.diodes.com for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. Automotive products are AEC-Q101 qualified and are PPAP capable. Automotive, AEC-Q101 and standard products are electrically and thermally the same, except where specified. For more information, please refer to http://www.diodes.com/quality/product_compliance_definitions/.
- $5.\ For\ packaging\ details,\ go\ to\ our\ website\ at\ http://www.diodes.com/products/packages.html.$

Marking Information



FZT 951 = Product Type Marking Code YWW = Date Code Marking Y or \overline{Y} = Last Digit of Year (ex: 5= 2015) WW or $\overline{W}W$ = Week Code (01~53)



Absolute Maximum Ratings (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V_{CBO}	-100	V
Collector-Emitter Voltage	$V_{\sf CEO}$	-60	V
Emitter-Base Voltage	V_{EBO}	-7	V
Continuous Collector Current	lc	-5	Α
Peak Pulse Current	I _{CM}	-15	Α

Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
Power Dissipation	(Note 6)		3.0 24	W	
Linear Derating Factor	(Note 7)	P _D	1.6 12.8	mW /°C	
Thermal Decistores, Junction to Ambient	(Note 6)	$R_{ heta JA}$	42		
Thermal Resistance, Junction to Ambient	(Note 7)	$R_{ heta JA}$	78	°C/W	
Thermal Resistance Junction to Lead (Note 8)		$R_{ heta JL}$	8.8		
Operating and Storage Temperature Range	T _{J,} T _{STG}	-55 to +150	°C		

ESD Ratings (Note 9)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	8,000	V	3B
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

Notes:

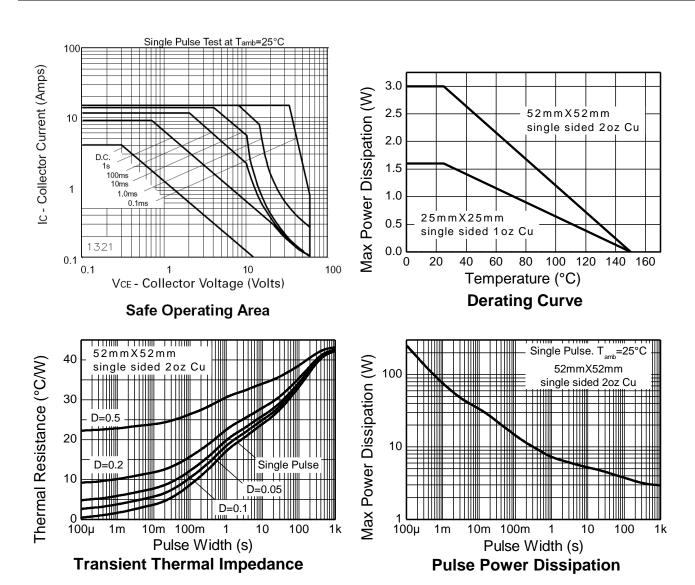
- 6. For a device mounted with the collector lead on 52mm x 52mm 2oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured under still air conditions whilst operating in steady-state.
- 7. Same as Note 6, except the device is mounted on 25mm x 25mm 1oz copper.
- 8. Thermal resistance from junction to solder-point (at the end of the collector lead).

 9. Refer to JEDEC specification JESD22-A114 and JESD22-A115.





Thermal Characteristics and Derating Information







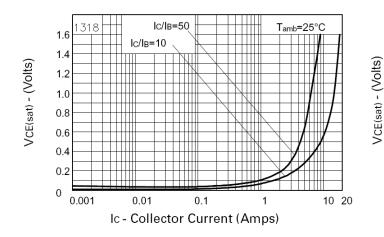
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

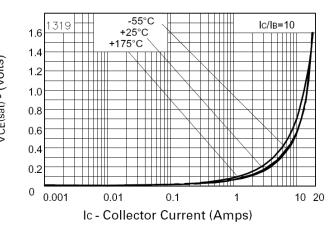
Characteristic	Symbol	Min	Тур.	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV _{CBO}	-100	-140	-	V	$I_{C} = -100 \mu A$
Collector-Emitter Breakdown Voltage (Note 10)	BV _{CER}	-100	-140	-	V	$I_C = -1\mu A, R_B \le 1k\Omega$
Collector-Emitter Breakdown Voltage (Note 10)	BV _{CEO}	-60	-90	-	V	$I_C = -10mA$
Emitter-Base Breakdown Voltage	BV _{EBO}	-7	-8	-	V	I _E = -100μA
Collector Cut-Off Current	I _{CBO}	-	<1 -	-50 -1	nA μA	V _{CB} = -80V V _{CB} = -80V, T _A = +100°C
Collector Cut-Off Current	I _{CER} R≤1kΩ	-	<1 -	-50 -1	nA μA	V _{CB} = -80V V _{CB} = -80V, T _A = +100°C
Emitter Cut-Off Current	I _{EBO}	-	<1	-10	nA	V _{EB} = -6V
		100	200	-	-	I _C = -10mA, V _{CE} = -1V
DC Current Transfer Static Ratio (Note 10)		100	200	300		I _C = -2A, V _{CE} = -1V
DC Current Transfer Static Ratio (Note 10)	h _{FE}	75	90	-		I _C = -5A, V _{CE} = -1V
		10	25	-		I _C = -10A, V _{CE} = -1V
	.,	-	-20	-50	mV	I _C = -100mA, I _B = -10mA
Callegator Emitter Seturation Valtage (Note 10)		-	-85	-140		$I_C = -1A$, $I_B = -100mA$
Collector-Emitter Saturation Voltage (Note 10)	$V_{CE(sat)}$	-	-155	-210	IIIV	$I_C = -2A$, $I_B = -200mA$
		-	-370	-460		$I_C = -5A$, $I_B = -500mA$
Base-Emitter Saturation Voltage (Note 10)	V _{BE(sat)}	-	-1080	-1240	mV	$I_C = -5A$, $I_B = -500mA$
Base-Emitter Turn-On Voltage (Note 10)	V _{BE(on)}	=	-935	-1070	mV	$I_{C} = -5A$, $V_{CE} = -1V$
Transitional Frequency (Note 10)	f _T	-	120	-	MHz	I _C = -100mA, V _{CE} = -10V, f = 50MHz
Output Capacitance	C _{obo}	-	74	-	pF	$V_{CB} = -10V$, $f = 1MHz$
Switching Time	t _{ON}	-	82	-	ns	V _{CC} = -10V, I _C = -2A,
Switching fillie	toff	-	350	-	115	$I_{B1} = -I_{B2} = -200 \text{mA}$

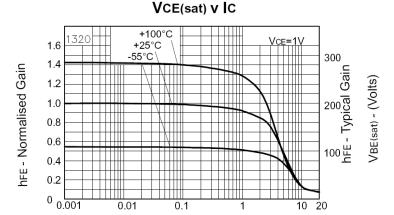
Note: 10. Measured under pulsed conditions. Pulse width \leq 300 μ s. Duty cycle \leq 2%.

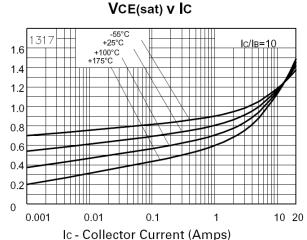


Typical Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)





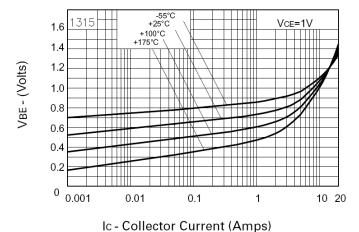




Ic - Collector Current (Amps)



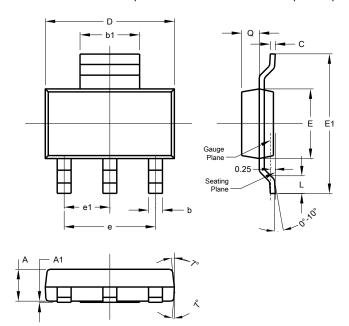






Package Outline Dimensions

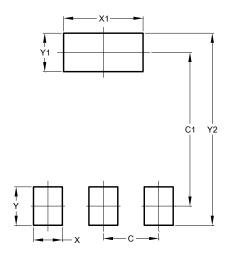
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.



SOT223				
Dim	Min	Max	Тур	
Α	1.55	1.65	1.60	
A 1	0.010	0.15	0.05	
b	0.60	0.80	0.70	
b1	2.90	3.10	3.00	
C	0.20	0.30	0.25	
D	6.45	6.55	6.50	
Е	3.45	3.55	3.50	
E1	6.90	7.10	7.00	
е	-	-	4.60	
e1	-	-	2.30	
٦	0.85	1.05	0.95	
Ø	0.84	0.94	0.89	
All Dimensions in mm				

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
С	2.30
C1	6.40
Х	1.20
X1	3.30
Y	1.60
Y1	1.60
Y2	8.00





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